# NSN 5961-00-724-2097

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Inclosure Material:

Metal

**Overall Length:** 

0.546 inches

#### **Overall Diameter:**

1.281 inches

#### **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

# Features Provided:

Hermetically sealed case

Thread Size:

0.312 inches

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, emitter-to-base, collector open and 100.0 breakdown voltage, collector-to-emitter, base open

# **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 1.00 amperes source cutoff current

# Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

# **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

Fiig:

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